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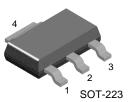


SEMICONDUCTOR

# **BSP50**

## **NPN Darlington Transistor**

- This device is designed for applications requiring extremly high current gain at collector currents to 500mA.
- Sourced from process 03.



1. Base 2. Collector 3. Emitter

## Absolute Maximum Ratings\* T<sub>a</sub>=25°C unless otherwise noted

| Symbol                            | Parameter  | Value       | Units<br>V |  |
|-----------------------------------|--|-------------|------------|--|
| V <sub>CER</sub>                  | Collector-Emitter Voltage                        | 45          |            |  |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 60          | V          |  |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 5           | V          |  |
| I <sub>C</sub>                    | Collector Current - Continuous                   | 800         | mA         |  |
| T <sub>J</sub> , T <sub>STG</sub> | Operating and Storage Junction Temperature Range | - 55 ~ +150 | °C         |  |

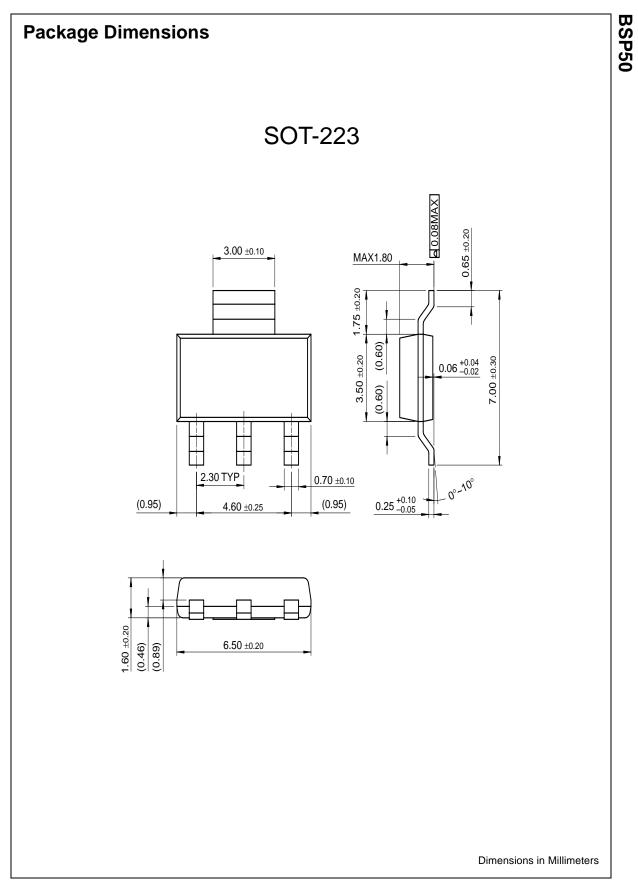
NOTES:
1) These ratings are based on a maximum junction temperature of 150°C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

| Symbol                | Parameter                            | Test Conditions                                | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| Off Charac            | teristics                            |  |      |      |      |       |
| V <sub>(BR)CBO</sub>  | Collector-Base Breakdown Voltage     | $I_{\rm C} = 100 \mu {\rm A}, I_{\rm E} = 0$   | 60   |      |      | V     |
| V <sub>(BR)EBO</sub>  | Emitter-Base Breakdown Voltage       | $I_{E} = 10\mu A, I_{C} = 0$                   | 5    |      |      | V     |
| ICES                  | Collector Cutoff Current             | $V_{CE} = 45V, V_{BE} = 0$                     |      |      | 50   | nA    |
| I <sub>EBO</sub>      | Emitter Cutoff Current               | $V_{EB} = 4.0 V, I_{C} = 0$                    |      |      | 50   | nA    |
| On Charac             | teristics                            |  |      |      |      |       |
| h <sub>FE</sub>       | DC Current Gain                      | I <sub>C</sub> = 150mA, V <sub>CE</sub> = 10V  | 1000 |      |      |       |
|                       |                                      | I <sub>C</sub> = 500mA, V <sub>CE</sub> = 10V  | 2000 |      |      |       |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 500mA, I <sub>B</sub> = 0.5mA |      |      | 1.3  | V     |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage      | I <sub>C</sub> = 500mA, I <sub>B</sub> = 0.5mA |      |      | 1.9  | V     |

## Thermal Characteristics $T_A=25^{\circ}C$ unless otherwise noted

| Symbol           | Parameter                               | Max. | Units |  |
|------------------|---|------|-------|--|
| PD               | Total Device Dissipation                | 1000 | mW    |  |
|                  | Derate above 25°C                       | 8.0  | mW/°C |  |
| R <sub>0JA</sub> | Thermal Resistance, Junction to Ambient | 125  | °C/W  |  |



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| Bottomless™                          | FPS™                           | MICROCOUPLER™                | PowerTrench <sup>®</sup>        | SuperSOT™-6              |
| CoolFET™                             | FRFET™                         | MicroFET™                    | QFET <sup>®</sup>               | SuperSOT <sup>™</sup> -8 |
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|--------------------------|---------------------------|---|
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#### Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург, Промышленная ул, дом № 19, литера Н, помещение 100-Н Офис 331